

# Preliminary

Mitsubishi Semiconductors < GaN HEMT >

## MGF0846G

40 W GaN HEMT [ non-matched ]

### DESCRIPTION

The MGF0846G, GaN HEMT with an N-channel schottky Gate, is designed for MMDS/UMTS/WiMAX applications.

### FEATURES

- High voltage operation :  $V_{DS} = 47\text{ V}$
- High output power :  $P_o = 46.0\text{ dBm (typ.) @ P3dB}$
- High efficiency :  $\eta_d = 60\% \text{ (typ.) @ P3dB}$
- Designed for use in Class AB linear amplifiers

### APPLICATIONS

- MMDS/UMTS/WiMAX

### QUALITY

- GG

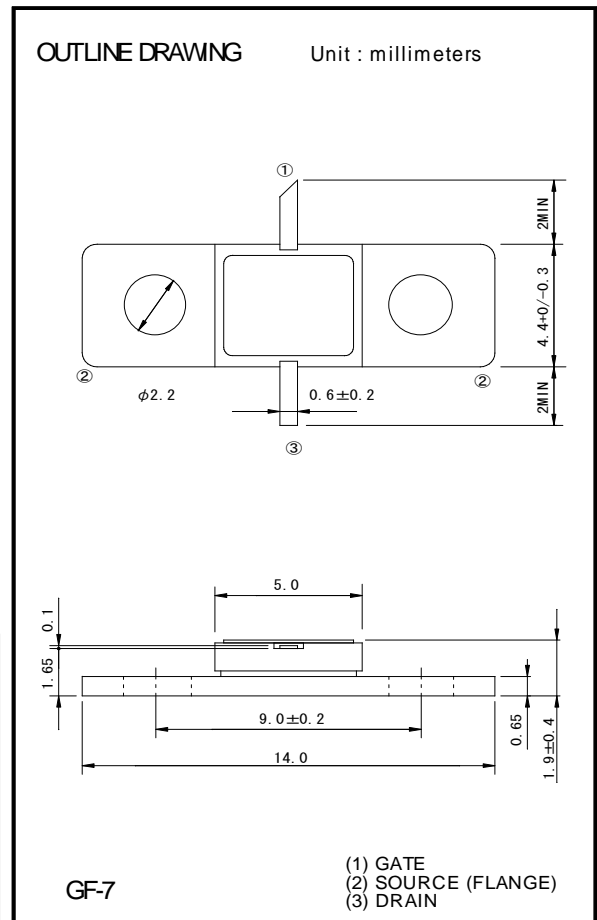
### RECOMMENDED BIAS CONDITIONS

- $V_{ds} = 47\text{ V}$  •  $I_{ds} = 340\text{ mA}$  •  $R_g = 30\ \Omega$

**Packaging** 4 inch Tray ( 25 pcs)

### Absolute maximum ratings ( $T_a = 25^\circ\text{ C}$ )

Symbol	Parameter	Ratings	Unit
VDS	Drain to Source Voltage	120	V
VGS	Gate to Source Voltage	- 10	V
PT	Total power dissipation	64	W
IGR	Reverse gate current	- 6	mA
IGF	Forward gate current	+ 120	mA
Tch	Channel temperature	230	°C
Tstg	Storage temperature	- 65 to +175	°C



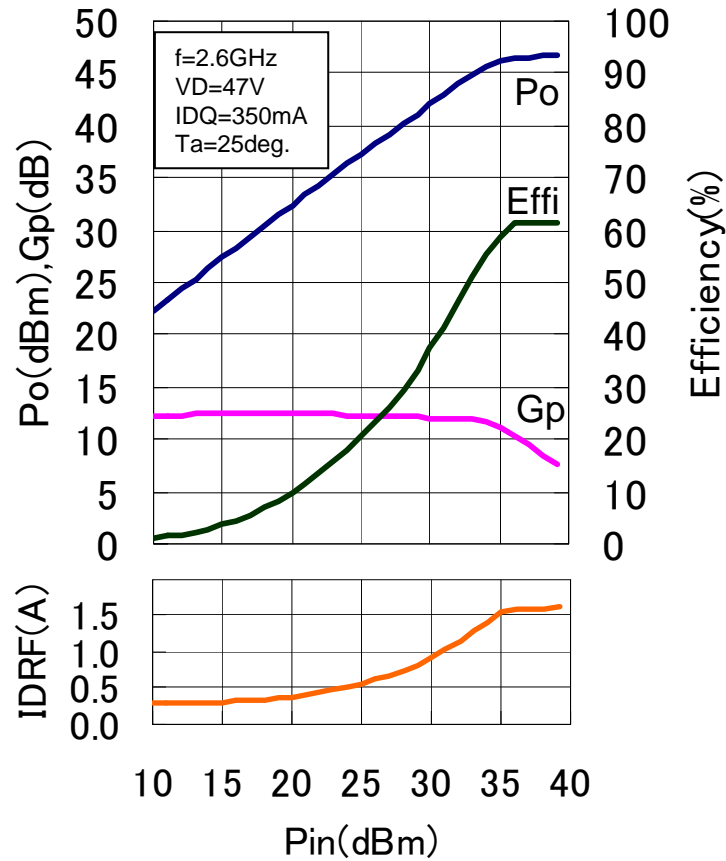
### Electrical characteristics ( $T_a = 25^\circ\text{ C}$ )

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
VGS(off)	Gate to source cut-off voltage	$V_{DS} = 47\text{ V}, I_{DS} = 12\text{ mA}$	-1.0	-	-5.0	V
P3dB	3dB gain compression power	$V_{DS} = 47\text{ V}, I_{DQ} = 340\text{ mA}, f = 2.6\text{ GHz}$	45.0	46.0	-	dBm
$\eta_d$	Drain efficiency		-	60	-	%
GLP *1	Linear power gain	*1 : $P_{in} = 20\text{ dBm}$	11.0	12.0	-	dB
Rth(ch-c)	Thermal resistance *2	$\Delta V_f$ Method	-	2.5	3.2	°C/W

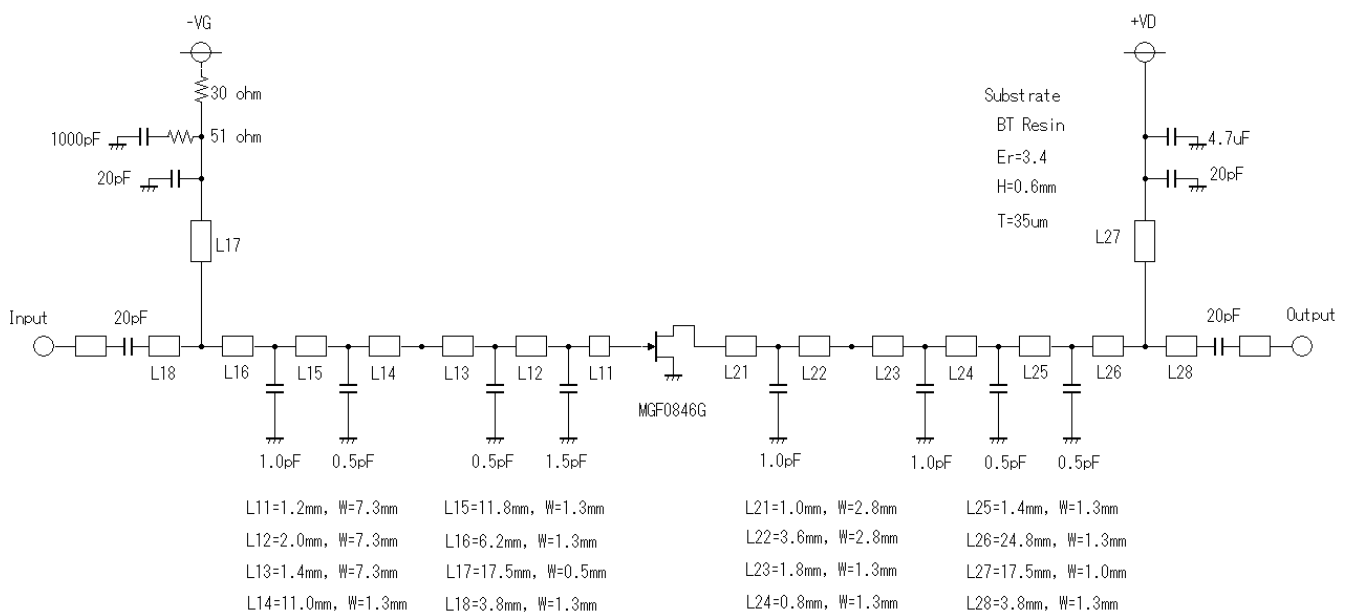
\*2 : Channel to case

Specifications are subject to change without notice.

### Example of Circuit Schematic and Characteristics : f = 2.6 GHz



### Example of circuit



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**MGF0846G**

40 W GaN HEMT [ non-matched ]

**S-parameters:**

Condition: VD = 47 V, ID = 350 mA, Ta = 25 deg. C

Freq. (GHz)	S11		S21		S12		S22	
	(mag)	(ang)	(mag)	(ang)	(mag)	(ang)	(mag)	(ang)
0.6	0.966	-173.6	5.549	85.5	0.029	30.5	0.660	-173.7
1.0	0.910	-176.4	3.379	74.4	0.028	3.6	0.643	-179.5
1.4	0.893	176.6	2.433	66.6	0.027	9.1	0.632	178.5
1.8	0.903	174.0	1.992	59.5	0.029	6.7	0.632	178.4
2.2	0.897	168.3	1.675	52.0	0.033	-1.2	0.648	175.2
2.6	0.909	163.9	1.402	42.0	0.026	4.1	0.664	173.0
3.0	0.875	157.0	1.293	34.7	0.031	-1.7	0.628	168.0
3.4	0.905	151.1	1.206	25.6	0.034	11.6	0.635	162.8
3.8	0.894	144.3	1.051	15.3	0.048	1.3	0.644	158.0
4.2	0.907	140.7	0.945	7.4	0.036	-19.0	0.666	152.3
4.6	0.911	136.7	0.853	1.2	0.038	-22.2	0.682	147.7
5.0	0.908	134.5	0.793	-4.8	0.035	-5.2	0.702	144.5
5.4	0.901	130.9	0.728	-10.9	0.039	-3.8	0.715	142.1
5.8	0.894	126.8	0.695	-18.1	0.041	-9.1	0.740	139.3
6.2	0.891	119.4	0.658	-25.5	0.046	-12.4	0.742	137.2
6.6	0.887	110.9	0.630	-33.8	0.049	-14.7	0.751	133.2
7.0	0.894	99.5	0.600	-43.6	0.049	-22.0	0.735	127.9
7.4	0.899	91.5	0.570	-51.5	0.056	-25.4	0.731	120.9
7.8	0.902	83.8	0.530	-60.5	0.052	-32.9	0.733	113.1
8.2	0.906	78.8	0.500	-68.5	0.058	-36.3	0.756	103.9

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